



MMF200N090DA

MMF200N090DK

900V 200A FRED Module

RoHS Compliant

October 2010

PRELIMINARY

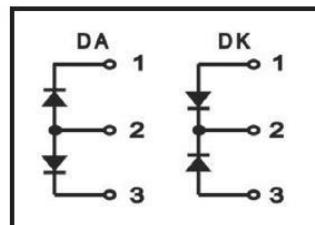
PRODUCT FEATURES

- Ultrafast Reverse Recovery Time
- Soft Reverse Recovery Characteristics
- Low Reverse Recovery Loss
- Low Forward Voltage
- High Surge Current Capability
- Low Inductance Package



APPLICATIONS

- Inversion Welder
- Uninterruptible Power Supply (UPS)
- Plating Power Supply
- Ultrasonic Cleaner and Welder
- Converter & Chopper
- Power Factor Correction (PFC) Circuit



ABSOLUTE MAXIMUM RATINGS

T_C=25°C unless otherwise specified

Symbol	Parameter	Test Conditions	Values	Unit
V _R	Maximum D.C. Reverse Voltage		900	V
V _{RRM}	Maximum Repetitive Reverse Voltage		900	V
I _{F(AV)}	Average Forward Current	T _C =90°C, Per Diode	100	A
		T _C =90°C, Per Moudle	200	A
		T _C =90°C, 20KHz, Per Moudle	141	A
I _{F(RMS)}	RMS Forward Current	T _C =90°C, Per Diode	141	A
I _{FSM}	Non-Repetitive Surge Forward Current	T _J =45°C, t=10ms, 50Hz, Sine	1080	A
		T _J =45°C, t=8.3ms, 60Hz, Sine	1160	A
I ² t	I ² t (For Fusing)	T _J =45°C, t=10ms, 50Hz, Sine	5832	A ² s
		T _J =45°C, t=8.3ms, 60Hz, Sine	6728	A ² s
P _D	Power Dissipation		360	W
T _J	Junction Temperature		-40 to +150	°C
T _{STG}	Storage Temperature Range		-40 to +125	°C
V _{isol}	Insulation Test Voltage	AC, t=1min	3000	V
Torque	Module-to-Sink	Recommended (M5)	2.5~4	N·m
Torque	Module Electrodes	Recommended (M5)	2.5~4	N·m
R _{θJC}	Thermal Resistance	Junction-to-Case	0.35	°C /W
Weight			100	g

ELECTRICAL CHARACTERISTICS

$T_C = 25^\circ\text{C}$ unless otherwise specified

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Unit
I_{RM}	Reverse Leakage Current	$V_R = 900\text{V}$	--	--	1	mA
		$V_R = 900\text{V}, T_J = 125^\circ\text{C}$	--	--	5	mA
V_F	Forward Voltage	$I_F = 100\text{A}$	--	2.75	--	V
		$I_F = 100\text{A}, T_J = 125^\circ\text{C}$	--	1.9	--	V
t_{rr}	Reverse Recovery Time	$I_F = 1\text{A}, V_R = 30\text{V}, di_F/dt = -200\text{A}/\mu\text{s}$	--	42	--	ns
t_{rr}	Reverse Recovery Time	$V_R = 450\text{V}, I_F = 100\text{A}$	--	65	--	ns
I_{RRM}	Max. Reverse Recovery Current	$di_F/dt = -200\text{A}/\mu\text{s}, T_J = 25^\circ\text{C}$	--	6	--	A
t_{rr}	Reverse Recovery Time	$V_R = 450\text{V}, I_F = 100\text{A}$	--	175	--	ns
I_{RRM}	Max. Reverse Recovery Current	$di_F/dt = -200\text{A}/\mu\text{s}, T_J = 125^\circ\text{C}$	--	13.5	--	A

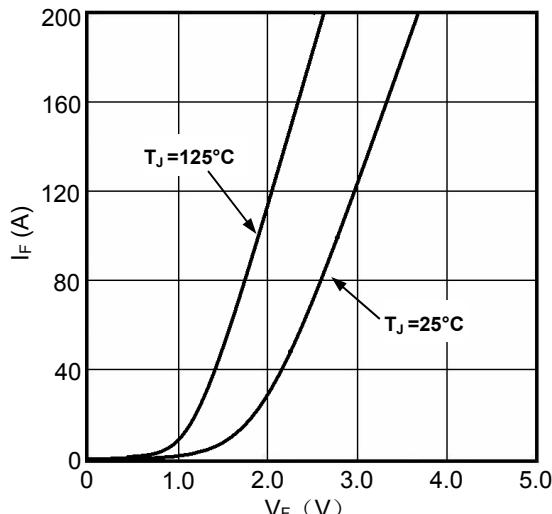


Figure 1. Forward Voltage Drop vs Forward Current

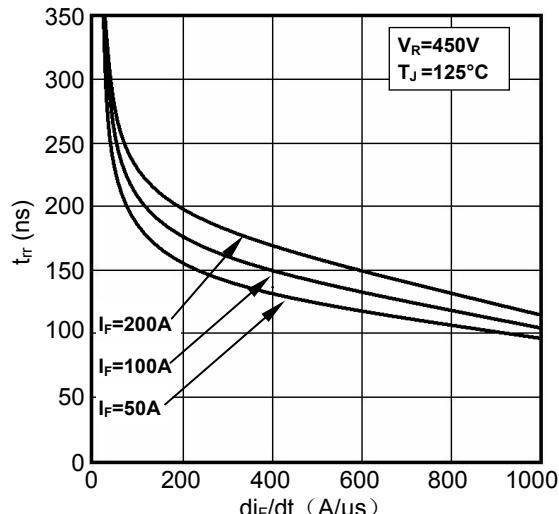


Figure 2. Reverse Recovery Time vs di_F/dt

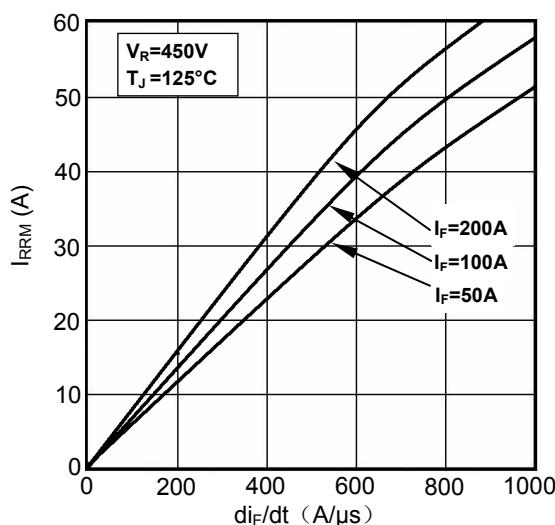


Figure 3. Reverse Recovery Current vs di_F/dt

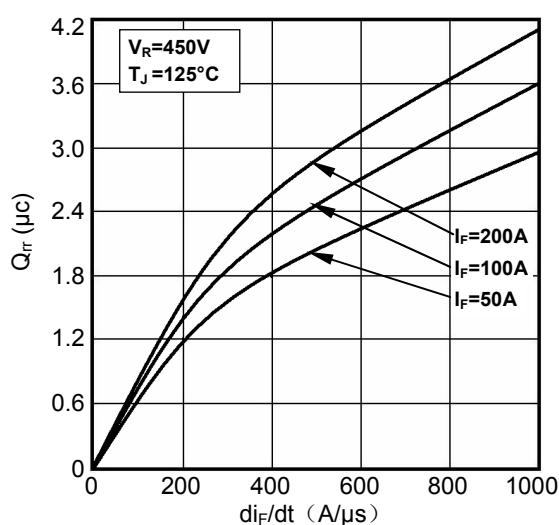


Figure 4. Reverse Recovery Charge vs di_F/dt

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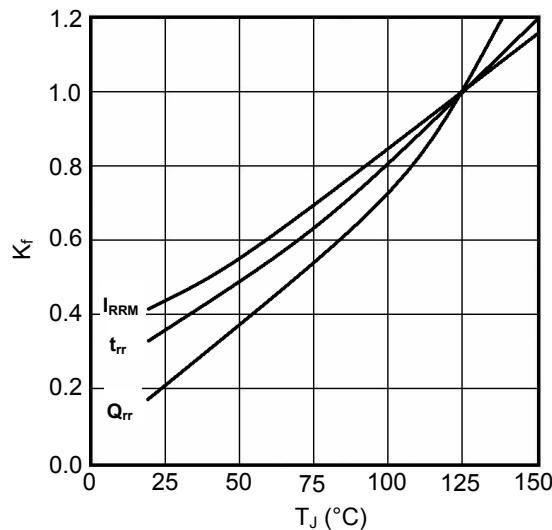


Figure5. Dynamic Parameters vs Junction Temperature

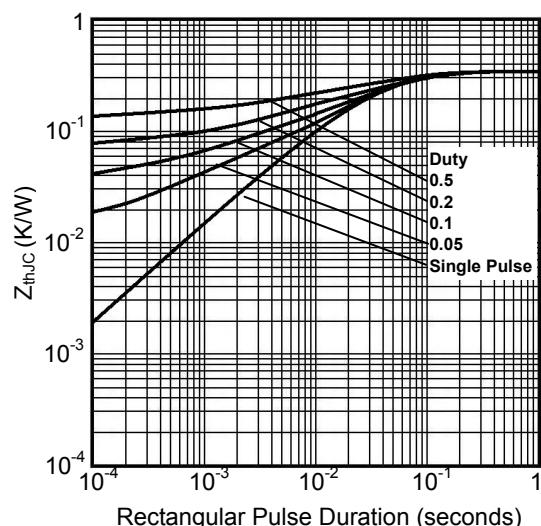
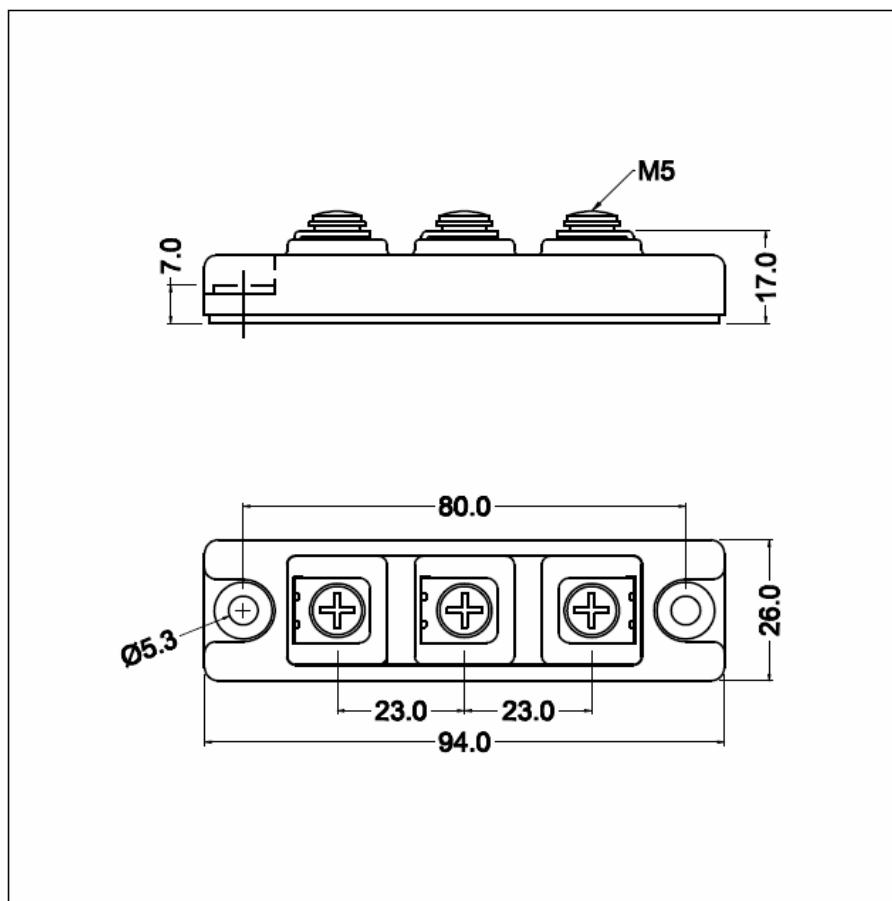


Figure6. Transient Thermal Impedance



Dimensions (mm)
 Figure7. Package Outline